

CMRDM7590

**SURFACE MOUNT
DUAL P-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET**

ATTOmini™**SOT-963 CASE**

- Device is *Halogen Free* by design

APPLICATIONS:

- Load/Power switches
- Power supply converter circuits
- Battery powered portable devices

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	8.0	V
Continuous Drain Current (Steady State)	I_D	140	mA
Continuous Drain Current, $t_p \leq 5.0\text{s}$	I_D	180	mA
Power Dissipation	P_D	125	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	Θ_{JA}	1000	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=5.0\text{V}, V_{DS}=0$			100	nA
I_{DSS}	$V_{DS}=5.0\text{V}, V_{GS}=0$			50	nA
I_{DSS}	$V_{DS}=16\text{V}, V_{GS}=0$			100	nA
BV_{DSS}	$V_{GS}=0, I_D=250\mu\text{A}$	20			V
$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.4		1.0	V
$r_{DS(\text{ON})}$	$V_{GS}=4.5\text{V}, I_D=100\text{mA}$		4.0	5.0	Ω
$r_{DS(\text{ON})}$	$V_{GS}=2.5\text{V}, I_D=50\text{mA}$		5.5	7.0	Ω
$r_{DS(\text{ON})}$	$V_{GS}=1.8\text{V}, I_D=20\text{mA}$		8.0	10	Ω
$r_{DS(\text{ON})}$	$V_{GS}=1.5\text{V}, I_D=10\text{mA}$		11	17	Ω
$r_{DS(\text{ON})}$	$V_{GS}=1.2\text{V}, I_D=1.0\text{mA}$		20		Ω
g_{FS}	$V_{DS}=5.0\text{V}, I_D=125\text{mA}$		140		mS
C_{rss}	$V_{DS}=15\text{V}, V_{GS}=0, f=1.0\text{MHz}$		4.0		pF
C_{iss}	$V_{DS}=15\text{V}, V_{GS}=0, f=1.0\text{MHz}$		10		pF
C_{oss}	$V_{DS}=15\text{V}, V_{GS}=0, f=1.0\text{MHz}$		3.7		pF
$Q_{g(\text{tot})}$	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$		0.50		nC
Q_{gs}	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$		0.17		nC
Q_{gd}	$V_{DS}=10\text{V}, V_{GS}=4.5\text{V}, I_D=100\text{mA}$		0.11		nC
t_{on}	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=200\text{mA}$		35		ns
t_{off}	$V_{DD}=10\text{V}, V_{GS}=4.5\text{V}, I_D=200\text{mA}$		100		ns

www.centralsemi.com**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMRDM7590 is an enhancement-mode dual P-Channel MOSFET designed for high speed pulsed amplifier and driver applications. This MOSFET offers low $r_{DS(\text{ON})}$ and low threshold voltage.

MARKING CODE: CW**FEATURES:**

- Power dissipation: 125mW
- Low package profile: 0.5mm (MAX)
- Low $r_{DS(\text{ON})}$
- Low threshold voltage
- Logic level compatibility
- Small SOT-963 surface mount package

SYMBOLV_{DS}

20

V

SYMBOLV_{GS}

8.0

V

SYMBOLI_D

140

mA

SYMBOLI_D

180

mA

SYMBOLP_D

125

mW

SYMBOLT_J, T_{stg}

-65 to +150

°C

SYMBOLθ_{JA}

1000

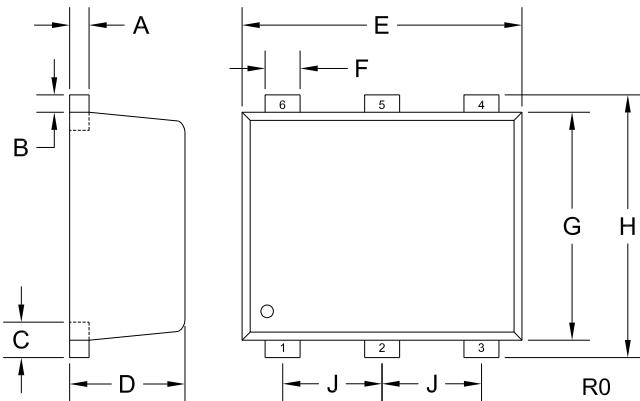
°C/W

CMRDM7590

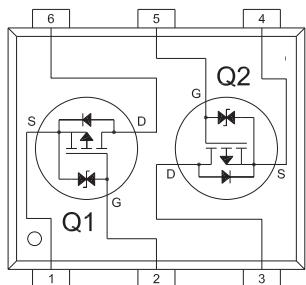
SURFACE MOUNT
DUAL P-CHANNEL
ENHANCEMENT-MODE
SILICON MOSFET



SOT-963 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



LEAD CODE:

- 1) Source Q1
- 2) Gate Q1
- 3) Drain Q2
- 4) Source Q2
- 5) Gate Q2
- 6) Drain Q1

MARKING CODE: CW

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.002	0.006	0.050	0.150
B	0.002	0.006	0.050	0.150
C	0.005	0.007	0.125	0.175
D	0.016	0.020	0.400	0.500
E	0.037	0.041	0.950	1.050
F	0.004	0.008	0.100	0.200
G	0.030	0.033	0.750	0.850
H	0.037	0.041	0.950	1.050
J	0.014		0.350	

SOT-963 (REV: R0)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
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- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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